	ESC	C	D	OCUMENT	CHANGE REQUEST		
DCR number	449	Changes rec	uired for: N//	Ą	Originator: Benoit Cornanguer		
Date: 2008/12	2/04	Date sent: 2	2008/12/04		Organisation: CNES		
Status: IMPLE	MENTED						
Title:	Diodes Switching	, based on types	s 1N5807 throu	ugh 1N5811			
Number:	5101/013		Issue:	1			
Other document	ts affected:						
Page:							
Page 5: Table 1 Page 5: Table 1 Page 7: Figure Page 8: Figure Page 8: Figure Page 9: paragra	Page 5: Table 1(a) - Type Variants Page 5: Table 1(b) - Maximun Ratings Page 7: Figure 1 - Parameter Derating Information Page 8: Figure 2 - Physical Dimensions Page 8: Figure 3 - Functional Diagram Page 9: paragraph 4.2.2 Deviations from Final Productio						
Paragraph:							
Page 5: Table 1(a) - Type Variants Page 5: Table 1(b) - Maximun Ratings Page 7: Figure 1 - Parameter Derating Information Page 8: Figure 2 - Physical Dimensions Page 8: Figure 3 - Functional Diagram Page 9: paragraph 4.2.2 Deviations from Final Productio							
Original wording	g:						
Proposed wording:							
See attached de	See attached document						
Justification:							
New variants 11 & 12 introduction with LCC2 B package (gold finish and hot solder dip).							

Attachments:
DCR_1N5811.pdf, null
Modifications:
N/A
Approval signature:
R. C. Hari-9
Date signed:
2008-12-04

TABLE 1(a)- Type Variants

Variant	Based on Type	Case	Figure	Breakdown Voltage V(BR) (V)	Working Peak Reverse Voltage VRWM (V)	Lead/Terminal Material and Finish
11	1N5811U	LCC2B	<mark>2(b)</mark>	<mark>150</mark>	<mark>150</mark>	2
<mark>12</mark>	1N5811U	LCC2B	<mark>2(b)</mark>	150	150	<mark>4</mark>

Justification .

Variant 11: new ST variant introduction with LCC2B package

Variant 12: new ST variant introduction with LCC2B package

TABLE 1(a)- MAXIMUM RATINGS

N°	Characteristics	Symbols	Maximum	Unit	Remarks
			Ratings		
1	Forward Surge Current				
	Variants 01 to 10	I _{FSM}	125	A(pk)	Note 1
	Variants 11 to 12		<mark>100</mark>	A	Note 5, Note 6
2	Working Peak Reverse Voltage				
	Variants 01 to 10	V _{RWM}	See Note 2		
	Variants 11 to 12		<mark>150</mark>	V	Note 6
3	Average Output Rectified Current			-	50%Duty Cycle
	Variants 01 to 10	Io	6	А	Note 3
	Variants 11 to 12		<mark>6</mark>	A	Note 7
4	Operating Temperature Range				
	Variants 01 to 10	Тор	-55 to +175	°C	Tamb
	Variants 11 to 12 (Case Temperature)	Top	-65 to +175	°C	Note 8
added	Junction Temperature	Tj	+175	°C	
	Variants 11 to 12				
5	Storage Temperature Range				
	Variants 01 to 10	Tstg	-65 to +200	°C	
	Variants 11 to 12		-65 to +175	°C	Note 8
6	Soldering Temperature				
	Variants 01 to 10	Tsol	+260	°C	Note 4
	Variants 11 to 12		+245	°C	Note 9
added	Thermal Resistance, Junction to Case	R _{th(j-c)}	<mark>6.5</mark>	°C/W	Note 10
	Variants 11 to 12				

NOTES:

5. Sinusoidal pulse of 10ms duration.

6. At Tamb $\leq +25^{\circ}$ C 7. At Tcase $\geq +136^{\circ}$ C, derate linearly to 0A at $+175^{\circ}$ C.

8. For Variant 12 with hot solder dip terminal finish all testing performed at Tamb>+125°C shall be carried out in a 100% inert atmosphere.

9. Duration 5 seconds maximum and the same package shall not be resoldered until 3 minutes have elapsed. 10. Package mounted on infinite heatsink.

Justification .



FIGURE 1 – PARAMETER DERATING INFORMATION (Not Applicable for the variants 11 to 12)



Justification.

Variant 11: new ST variant introduction with LCC2B package Variant 12: new ST variant introduction with LCC2B package Figure 2(b)- Variant 11 to 12 - Leadless Chip Carrier 2 (LCC2B) – 2 Terminal



Notes:

- 1. The anode is identified by metallization in two top castellation and by the index mark on the bottom metallization n°1.
- 2. Measurement prior to solder coating the mounting pads on bottom of package.

Justification .

Variant 11: new ST variant introduction with LCC2B package

Variant 12: new ST variant introduction with LCC2B package



FIGURE 3 - FUNCTIONAL DIAGRAM

Variants 11 to 12

Terminal 1: Anode Terminal 2: Cathode



Notes:

1. For LCC2, the lid is not connected to any lead.

Justification .

Variant 11: new ST variant introduction with LCC2B package Variant 12: new ST variant introduction with LCC2B package

4.2.2 Deviations from Final Production Tests (Chart II)

(a) Para. 9.2.1, Bond Strenght Test: Not applicable; excepted for the variants 11 to 12 (Applicable in the Chart F2 of the ESCC N°5000 Issue 3).

(b) Para. 9.2.2, Die Shear Test: Not applicable; excepted for the variants 11 to 12 (Applicable in the Chart F2 of the ESCC N°5000 Issue 3).

(c) Para. 9.8.1, Seal Test Fine Leak: Not applicable excepted for the variants 11 to 12 (Applicable in the Chart F3 of the ESCC N°5000 Issue 3).

(d) Surge currentExcepted for the variants 11 to 12: N/A.

Justification .

Variant 11: new ST variant introduction with LCC2B package Variant 12: new ST variant introduction with LCC2B package

4.2.3 Deviations from Burn-In and Electrical Measurements (Chart III)

(a) H.T.R.B Test: Not applicable excepted for the variants 11 to 12

Justification .

Variant 11: new ST variant introduction with LCC2B package Variant 12: new ST variant introduction with LCC2B package

4.2.4 Deviations from Qualification Tests (Chart IV)

(a) Para. 9.2.3, Bond Strenght Test: Not applicable excepted for the variants 13 to 14 (Applicable in the Chart F4 Subgroup 3 of the ESCC N°5000 Issue 3).

(b) Para. 9.2.4, Die Shear Test: Not applicable excepted for the variants 13 to 14 (Applicable in the Chart F4 Subgroup 3 of the ESCC N°5000 Issue 3).

Justification .



4.3.2 Weight

The maximum weight of the diodes specified herein shall be 0.25 grams for the variants 01 to 10, 0.18 grams for the variants 11 to 12.

Justification .

Variant 11: new ST variant introduction with LCC2B package Variant 12: new ST variant introduction with LCC2B package

4.3.3 Terminal Strength

For the variants 11 to 12: MIL-STD-883 test method 2004 Cond D (Applicable in the Chart F4 Subgroup 3 of the ESCC N°5000 Issue 3).

4.4.1 Case

The case shall be hermetically sealed and have an Aln body with kovar lid for the variants 11 to 12.

Justification .

Variant 11: new ST variant introduction with LCC2B package Variant 12: new ST variant introduction with LCC2B package

4.4.2 Lead Material and Finish

For the variants 11 to 12 leads/terminals as specified in the Table 1a.

Justification.

Variant 11: new ST variant introduction with LCC2B package Variant 12: new ST variant introduction with LCC2B package

4.5.1 General

For the variants 11 to 12 the marking shall be in accordance with the requirements of ESCC Basic Specification No. 21700 and as follows.
The information to be marked on the component shall be:
(a) The ESCC qualified components symbol (for ESCC qualified components only).
(b) The ESCC Component Number.
(c) Traceability information.

Justification .

Variant 11: new ST variant introduction with LCC2B package Variant 12: new ST variant introduction with LCC2B package

4.6.2 Electrical Measurements at high an Low Temperatures

The parameters to be measured at high and low temperatures are scheduled in Table 3. For the variants 01 to 10, the measured shall be performed at Tamb = +100 (+0-5). For the variants 11 to 12, the measured shall be performed at Tamb = +125 (+0-5) and tamb = $-65 (+5-0) ^{\circ}C$ respectively.

Justification .

Variant 11: new ST variant introduction with LCC2B package Variant 12: new ST variant introduction with LCC2B package

4.6.3 Circuits for Electrical Measurements

For the variants 11 to 12: Not Applicable.

Justification .



4.7.3 Conditions for Power Burn-in

The requirements for power burn-in are specified in Section 7 of ESA/SCC Generic Specification No. 5000.

For the variants 01 to 10 the conditions for power burn-in are specified in Table 5(a) of this specification.

For the variants 11 to 12 the conditions for power burn-in are specified in Table 5(b) of this specification.



TABLE 2 - ELECTRICAL MEASUREMENTS AT ROOM TEMPERATURE D.C.PARAMETERS

N°	Characteristics	Symbols	MIL-STD-750 Test Method	Test Conditions	Limits		Units
					Min	Max	
added	Forward	V _{F1}	4011	Pulse Method			
	voltage			I _F =3A,			
				Variants 11 to 12 (Note 2)		0.865	V
1	Forward	V _{F2}	4011	Pulse Method			
	Voltage			$I_{\rm F}=4A$, Variants 01 to 10	-	0.875	V
				Variants 11 to 12 (Note 2)	•	<mark>0.9</mark>	V
added	Forward	V _{F3}	4011	Pulse Method			
	voltage			I _F =6A,			
				Variants 11 to 12 (Note 2)		<mark>0.955</mark>	V
2	Reverse Current	I _R	4016	DC Method			
				v_R : see Note 1 Variant 01 to 10	-	5	μA
				V _R =150V Variants 11 to 12		<mark>5</mark>	μ <mark>Α</mark>

Notes

1. See Column (3) of Table1 (a)

Pulse test: $tp \le 680 \mu s$; Duty Cycle $\le 2\%$ 2.



TABLE 2 - ELECTRICAL MEASUREMENTS AT ROOM TEMPERATURE - A.C.PARAMETERS

N°	Characteristics	Symbols	MIL-STD-750	IL-STD-750 Test Conditions		Limits	
	Characteristics	Bymbols	Test Method	Test Conditions	Min	Max	Omts
3	Junction Capacitance	CJ	4001	Variant 01 to 10 V _R =10Vdc; f=1MHz	-	50	pF
				Variant 11 to 12 $V_R=10Vdc; f=1MHz$ Vsig=50mV(p-p)max (Note 1)	-	<mark>60</mark>	pF
4	Reverse Recovery Time	t _{rr}	4031	$\label{eq:array} \begin{array}{l} \hline \textbf{Variants 01 to 10} \\ I_F = I_R = 1A; \ I_{RR} = 100 \text{mA}(\text{pk}) \\ DI_F / dt = -65 \text{A}/\mu\text{S} \end{array}$	-	30	ns
		t _{rr}	4031 Cond. 'B'	Variants 11 to 12 $I_F = 1A; V_R = 30V$ $DI_F/dt = -50A/\mu S$ (Note 1)	-	35	<mark>ns</mark>
added	Forward Recovery Time	t _{ír}	4026	Variants 11 to 12 $I_{FM} = 500mA$, $V_{fr} = 1.1 \times V_F$ (Note 1)	-	15	<mark>ns</mark>
added	Forward Recovery Voltage	V _{fr}	4026	Variants 11 to 12 I _{FM} = 500mA (Note 1)		2.2	V
added	Thermal Impedance Junction to Case	Z _{th(j-c)}	3101	Variants 11 to 12 $I_H=1$ to 10A; $t_H=50ms$ $I_M=50mA$; $t_{md}=100\mu s$ (Note 2)	Calcula see Not	te ΔV_F , te 3)	°C/W

NOTES

1. See appendix A [Agreed Deviations for STMicroelectronics (F)]

2. Performed only during Screening Tests Parameter Drift Values (Initial Measurements), go-no-go.

3. The limits for ΔVF shall be defined by the Manufacturer on every lot in accordance with MIL-STD-750 Method 3101 and shall guarantee the $R_{th(i-c)}$ limits specified in Maximum Ratings, go no go.

Justification .



TABLE 3- ELECTRICAL MEASUREMENTS AT HIGH TEMPERATURES

			MIL-STD-		Limits		
N°	Characteristics	Symbols	Test Method	(Note 4)	Min	Max	Units
added	Forward Voltage	V _{F2}	<mark>4011</mark>	Tamb= +125°C (+0 -5) Pulse Method $I_F=4A$, Note 5 Variants 11 to 12	ł	<mark>0.8</mark>	V
				Tamb= -65°C (+5 -0)Pulse Method I_F =4A, Note 5Variants 11 to 12	-	1.075	V
2	Reverse Current	I _R	4016	Variant 01 to 10 Tamb=+100°C(+0 -5) V_R : see Note 3	-	150	μΑ
				Variant 11 to 12 Tamb= +125°C (+0 -5) DC Method V-= 150V	-	30	μA

NOTES

4. Read and record measurements shall be performed on a sample of 5 components with 0 failures allowed. Alternatively a 100% inspection may be performed.
5. Pulse Width≤ 680µs; Duty Cycle ≤ 2%

Justification .



TABLE 4 – PARAMETER DRIFT VALUES

		Limit	S		
Characteristics	Symbols	Drift Value	Abs	olute	Units
		(Δ)	Min	Max	
Forward Voltage 2	V _{F2}	Variants 01 to 10 ± 100mV	-	875	mV
		Variants 11 to 12 ± 50mV	•	<mark>900</mark>	mV
Reverse Current	I _R	Variants 01 to 10 ± 1µA	-	5	μA
		Variants 11 to 12 $\pm 0.5\mu$ A or (1)	-	5	μA
		± 100%			

NOTES

1. Whichever is the greater referred to the initial value.

FIGURE 4 – CIRCUITS FOR ELECTRICAL MEASUREMENTS (Not Applicable for the variants 11 to 12)

Justification .

Variant 11: new ST variant introduction with LCC2B package Variant 12: new ST variant introduction with LCC2B package

TABLE 5(a) HIGH TEMPERATURE REVERSE BIAS BURN-IN CONDITIONS (Applicable for the variants 11 to 12)

Characteristics	Symbols	Test Conditions	Units
Ambiant Temperature	Tamb	+150 (+0 -5)	°C
Reverse Voltage	V _R	120	V
Duration	t	<u>≥ 48</u>	Hours

Justification .



TABLE 5(b) POWER BURN-IN AND OPERATING LIFE TEST CONDITIONS

FOR VARIANTS 11 TO 12

Characteristics	Symbols	Test Conditions	Units
Ambiant Temperature	Tamb	+22 (±3)	°C
Junction Temperature	Tj	+175 (+0 -5)	°C
Average Output Rectified Current	I _o	Note 1	A

NOTES:

1. The output current may be adjusted, within their given limit ranges, to attain the specified junction temperature.

Justification . Variant 11: new ST variant introduction with LCC2B package Variant 12: new ST variant introduction with LCC2B package

TABLE 6 - ELECTRICAL MEASUREMENTS AT INTERMEDIATE POINTS AND **ONCOMPLETION OF ENDURANCE TESTING**

No.	CHARACTERISTICS	SYMBOL	SPEC. AND/OR TEST METHOD	TEST CONDITIONS		IITS	UNIT
					MIN.	MAX.	
1	Forward Voltage Drop 2	V _{E2}	As per Table 2	As per Table 2			
1	Torward Voluge Drop 2	12	As per Table 2	Variant 01 to 10	-	0.875	V
added	Forward Voltage Drop 1	V _{E1}	As per Table 2	As per Table 2		0.865	V
audeu	Polward Voltage Drop 1	'FI	As per rable 2	Variant 11 to 12		0.805	×
added	Forward Voltage Drop 3		As per Table 2	As per Table 2		0.955	V
added	Torward Voltage Drop 5	15	As per radie 2	Variant 11 to 12		0.755	•
				As per Table 2			
2	Reverse Current	IR	As per Table 2	Variant 01 to 10	-	5.0	μA
				Variant 11 to 12		<mark>5.0</mark>	μ <mark>Α</mark>

Justification .



APPENDIX 'A'

AGREED DEVIATIO	ONS FOR STMICROELECTRONICS (F)
ITEMS AFFECTED	DESCRIPTION OF DEVIATIONS
Deviations from	Internal Visual Inspection: Wedge bonds equal to 1.1 wire diameter are acceptable for
Production Control-Chart F2	bonding with a V-Groove tool.
Deviations from Production Control-Chart F2	Special In-process Control Internal Visual Inspection. For CCP packages the criteria specified for voids in the filet and minimum die mounting material around the visible die perimeter for die mounting defects may be omitted providing that a radiographic inspection to verify the die-attach process is performed on a sample basis in accordance with STMicroelectronics procedure 7050651.
Deviations from Room Temperature Electrical Measurements	All AC characteristic (Room Electrical Temperature Electrical Measurements Characteristics: C, t_{rr} , t_{fr} , V_{fr}), may be considered guaranteed but not tested if successful pilot lot testing has been performed on the diffusion lot which includes AC characteristic measurements per the Detail Specification. A summary of the pilot lot testing shall be provided if required by the Purchase Order.